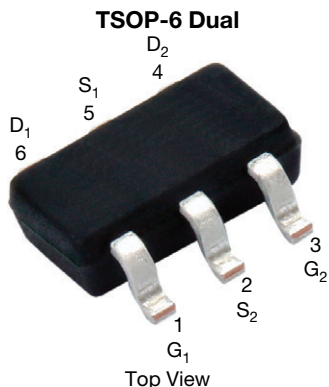


Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET



Marking code: 8X

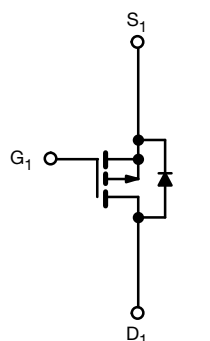
| PRODUCT SUMMARY | |
|--|--------|
| V_{DS} (V) | -30 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = -10$ V | -0.110 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V | -0.185 |
| I_D (A) | -2.75 |
| Configuration | Dual |
| Package | TSOP-6 |

FEATURES

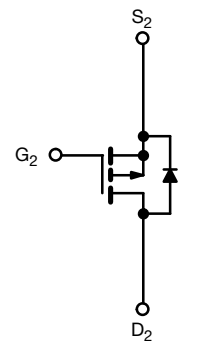
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE



P-Channel MOSFET



P-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted) | | | | |
|---|----------------|----------------|-------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-source voltage | | V_{DS} | -30 | V |
| Gate-source voltage | | V_{GS} | ± 20 | |
| Continuous drain current ($T_J = 150$ °C) ^a | $T_C = 25$ °C | I_D | -3 | A |
| | $T_C = 125$ °C | | -1.74 | |
| Pulsed drain current | | I_{DM} | -11 | |
| Continuous source current (diode conduction) ^a | | I_S | -2.1 | W |
| Maximum power dissipation ^a | $T_C = 25$ °C | P_D | 1.67 | |
| | $T_C = 125$ °C | | 0.56 | |
| Unclamped inductive surge UIS | | I_{AV} | -5 | A |
| Operating junction and storage temperature range | | T_J, T_{stg} | -55 to +175 | °C |

| THERMAL RESISTANCE RATINGS | | | | |
|--|--------------|------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Maximum junction-to-ambient ^a | Steady state | R_{thJA} | 150 | °C/W |
| Maximum junction-to-foot (drain) | Steady state | R_{thJF} | 90 | |

Note

a. Surface mounted on 1" x 1" FR4 board

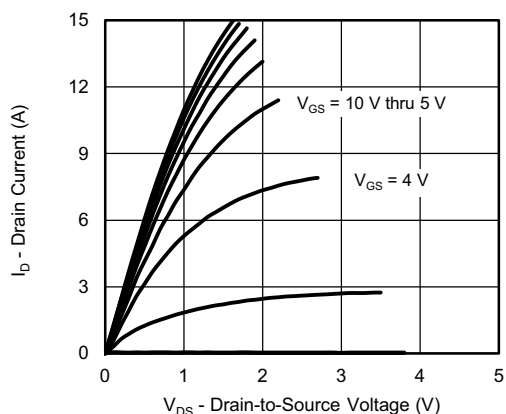
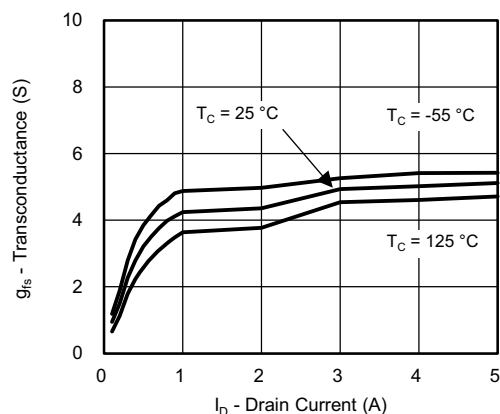
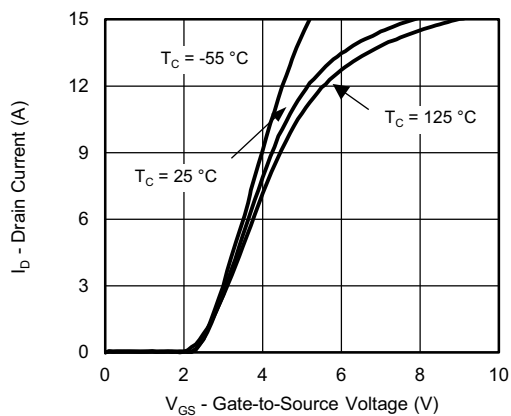
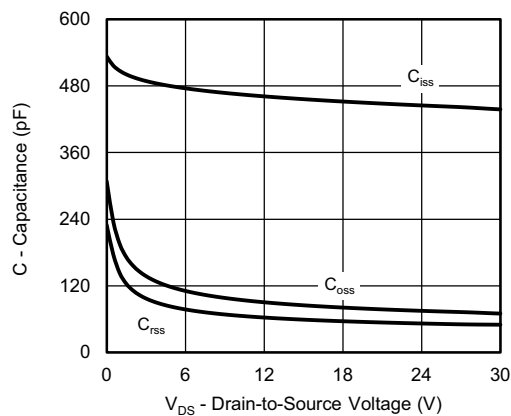
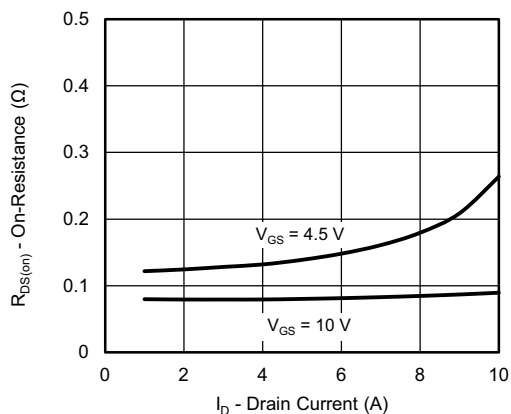
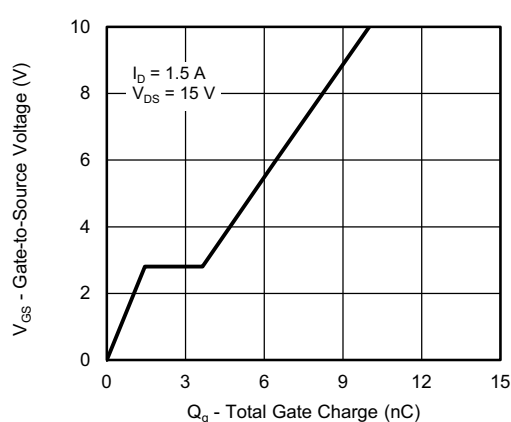


| SPECIFICATIONS (T _J = 25°C, unless otherwise noted) | | | | | | | |
|--|----------------------|--|--|------|-------|-------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | | |
| Gate threshold voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = -250 μA | | -1.5 | - | -2.5 | V |
| Gate-body leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = ± 20 V | | - | - | ± 100 | nA |
| Zero gate voltage drain current | I _{DSS} | V _{GS} = 0 V | V _{DS} = -30 V | - | - | -1 | μA |
| | | V _{GS} = 0 V | V _{DS} = -30 V, T _J = 175 °C | - | - | -50 | |
| On-state drain current ^a | I _{D(on)} | V _{GS} = -10 V | V _{DS} ≤ -5 V | -4 | - | - | A |
| Drain-source on-state resistance ^a | R _{DS(on)} | V _{GS} = -10 V | I _D = -1.5 A | - | 0.085 | 0.133 | Ω |
| | | V _{GS} = -4.5 V | I _D = -2 A | - | 0.135 | 0.185 | |
| Forward transconductance ^a | g _{fs} | V _{DS} = -5 V, I _D = -1 A | | - | 4.2 | - | S |
| Diode forward voltage ^a | V _{SD} | I _S = -0.5 A, V _{GS} = 0 V | | - | -0.83 | -1.10 | V |
| Dynamic ^b | | | | | | | |
| Input capacitance | C _{iss} | V _{GS} = 0 V | V _{DS} = -15 V | - | 456 | 570 | pF |
| Output capacitance | C _{oss} | | | - | 85 | 106 | |
| Reverse capacitance | C _{rss} | | | - | 59 | 74 | |
| Total gate charge | Q _g | V _{GS} = -10 V | V _{DS} = -15 V, I _D = -3 A | - | 9.7 | 12.2 | nC |
| Gate-source charge | Q _{gs} | | | - | 1.3 | - | |
| Gate-drain charge | Q _{gd} | | | - | 2 | - | |
| Gate resistance | R _g | f = 1 MHz | | 9 | - | 24 | Ω |
| Turn-on delay time | t _{d(on)} | V _{DD} = -10 V, R _L = 10 Ω, I _D ≅ -1 A, V _{GEN} = -10 V, R _g = 1 Ω | | - | 6.6 | 8.3 | ns |
| Rise time | t _r | | | - | 2.4 | 3 | |
| Turn-off delay time | t _{d(off)} | | | - | 18.4 | 23 | |
| Fall time | t _f | | | - | 2.2 | 2.8 | |
| Source-Drain Diode Ratings and Characteristic ^b | | | | | | | |
| Pulsed current | I _{SM} | | | - | - | -11 | A |
| Forward voltage | V _{SD} | I _F = 0.5 A, V _{GS} = 0 V | | - | -0.83 | -1.1 | V |
| Reverse recovery fall time | t _a | V _{DD} = -24 V, I _{FM} = -1.5 A, di/dt = 100 A/μs, R = 160 Ω, L = 1 mH, pulse W = 2 μs | | - | 9.1 | - | ns |
| Reverse recovery rise time | t _b | | | - | 4.8 | - | ns |
| Body diode reverse recovery time | t _{rr} | | | - | 14 | 28 | ns |
| Body diode reverse recovery charge | Q _{rr} | | | - | 9 | 18 | μC |
| Body diode peak reverse recovery current | I _{RM(REC)} | | | - | -1.4 | - | A |

Notes

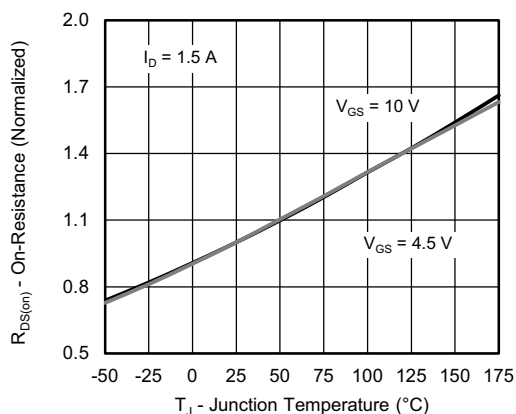
- a. Pulse test; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\ \%$
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

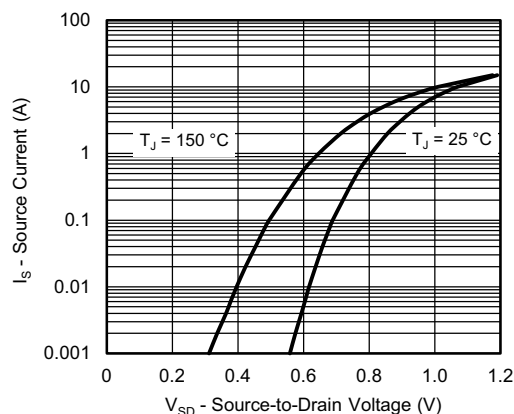
TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)

Output Characteristics

Transconductance

Transfer Characteristics

Capacitance

On-Resistance vs. Drain Current

Gate Charge



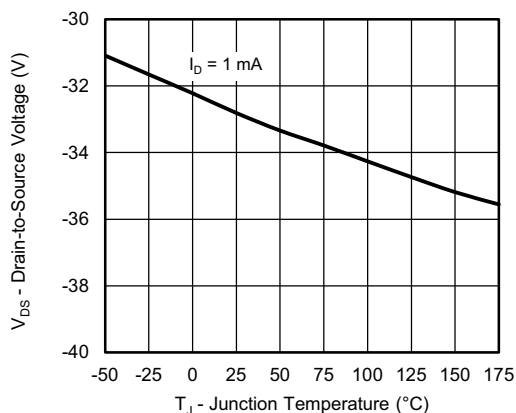
TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)



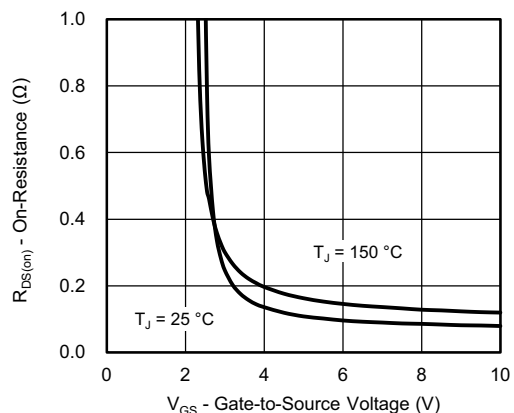
On-Resistance vs. Junction Temperature



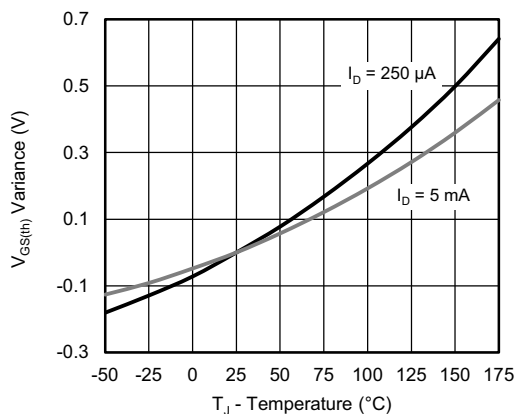
Source-Drain Diode Forward Voltage



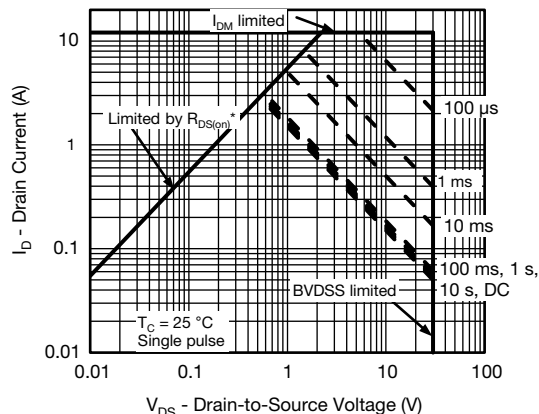
Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

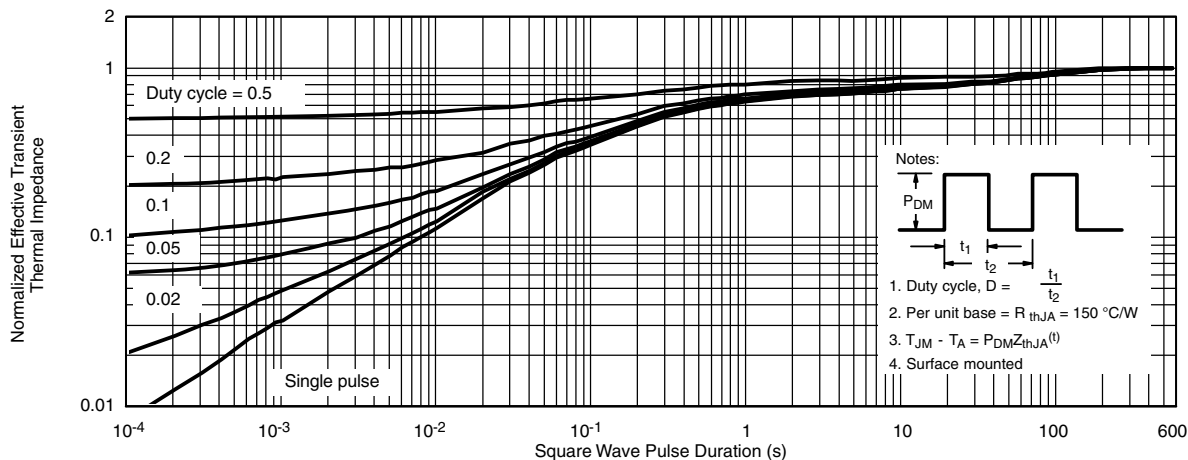


* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

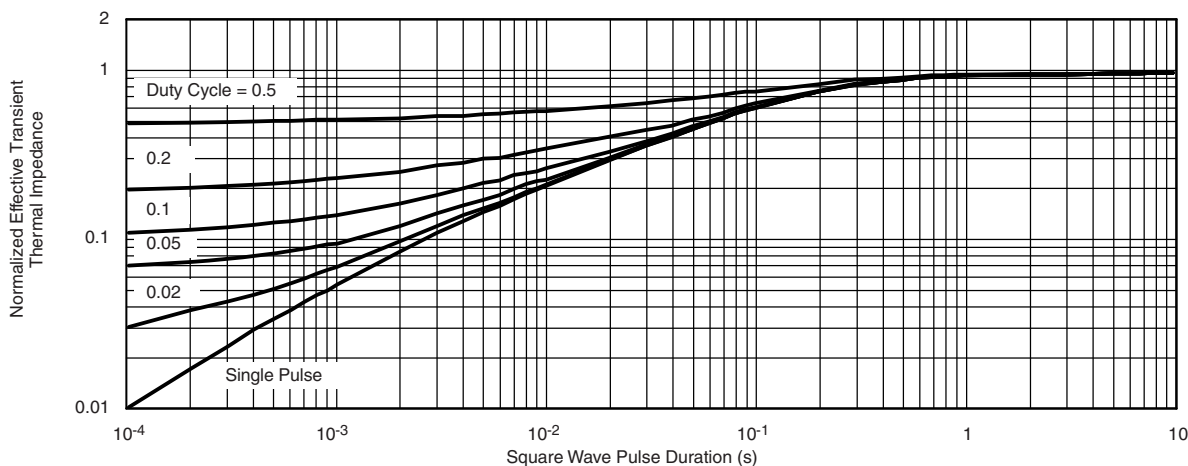
Safe Operating Area, Junction-to-Case



TYPICAL CHARACTERISTICS (25 °C unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



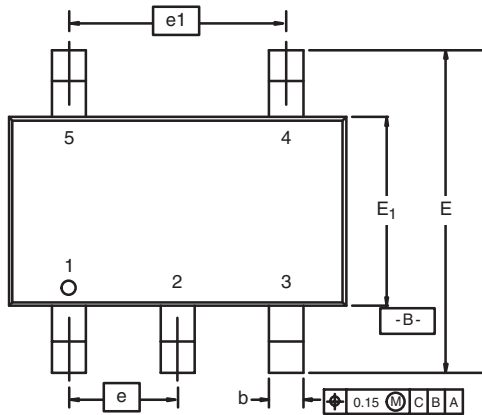
Normalized Thermal Transient Impedance, Junction-to-Foot

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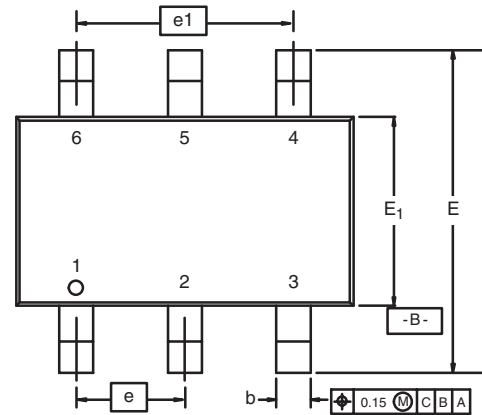


TSOP: 5/6-LEAD

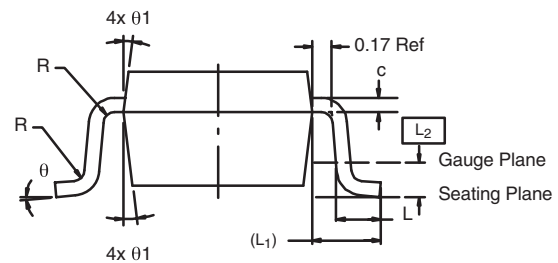
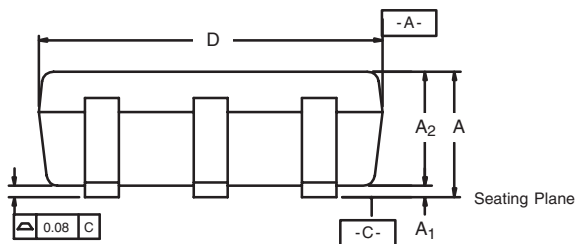
JEDEC Part Number: MO-193C



5-LEAD TSOP

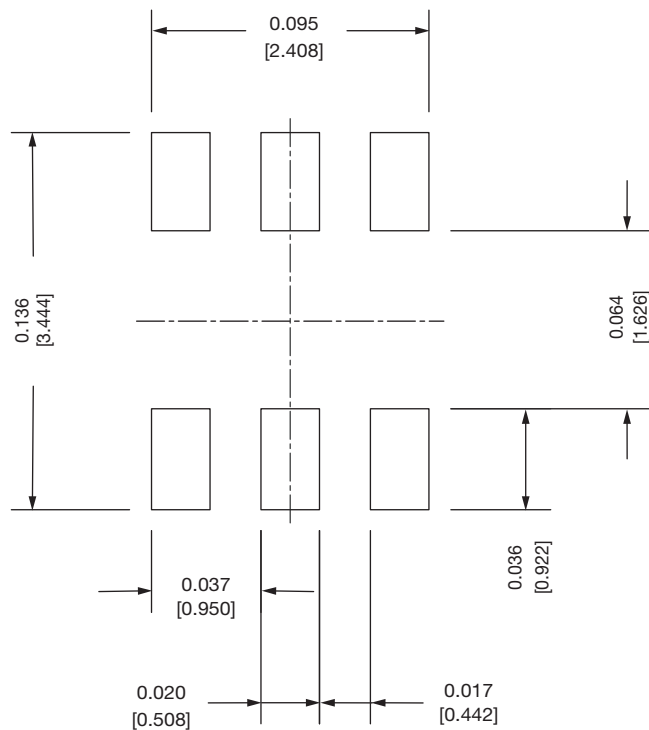
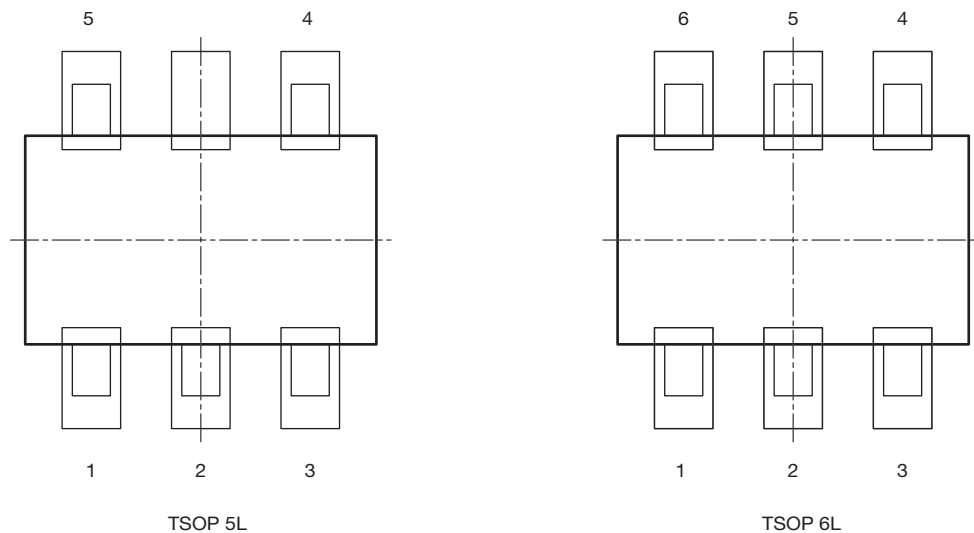


6-LEAD TSOP



| Dim | MILLIMETERS | | | INCHES | | |
|--------------------------------|-------------|------|------|------------|-------|-------|
| | Min | Nom | Max | Min | Nom | Max |
| A | 0.91 | - | 1.10 | 0.036 | - | 0.043 |
| A ₁ | 0.01 | - | 0.10 | 0.0004 | - | 0.004 |
| A ₂ | 0.90 | - | 1.00 | 0.035 | 0.038 | 0.039 |
| b | 0.30 | 0.32 | 0.45 | 0.012 | 0.013 | 0.018 |
| c | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| D | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 |
| E | 2.70 | 2.85 | 2.98 | 0.106 | 0.112 | 0.117 |
| E ₁ | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 |
| e | 0.95 BSC | | | 0.0374 BSC | | |
| e ₁ | 1.80 | 1.90 | 2.00 | 0.071 | 0.075 | 0.079 |
| L | 0.32 | - | 0.50 | 0.012 | - | 0.020 |
| L ₁ | 0.60 Ref | | | 0.024 Ref | | |
| L ₂ | 0.25 BSC | | | 0.010 BSC | | |
| R | 0.10 | - | - | 0.004 | - | - |
| θ | 0° | 4° | 8° | 0° | 4° | 8° |
| θ ₁ | 7° Nom | | | 7° Nom | | |
| ECN: C-06593-Rev. I, 18-Dec-06 | | | | | | |
| DWG: 5540 | | | | | | |

Recommended Land Pattern For TSOP-5L / TSOP-6L


Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022
DWG: 3010



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